



### Features

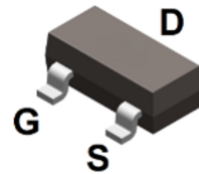
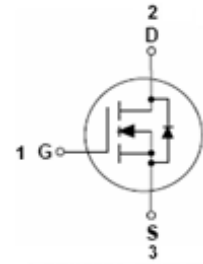
- Low input capacitance
- High  $V_{DSS}$  rating for power application
- Low input / output leakage

### Typical Applications

- Motor control
- DC-DC converters
- Power management functions

### Mechanical Data

- Case: SOT-23
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matted-Tin plated; Solderable Per MIL-STD-202, Method 208



SOT-23

### Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
BSS131	SOT-23	3000 pcs / Tape & Reel	131

### Maximum Ratings (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	$V_{DSS}$	240	V
Gate-to-Source Voltage	$V_{GSS}$	$\pm 20$	V
Continuous Drain Current ( $T_A = 25^\circ\text{C}$ )	$I_D$	0.11	A
Continuous Drain Current ( $T_A = 70^\circ\text{C}$ )	$I_D$	0.09	A
Pulsed Drain Current ( $t_p = 10\mu\text{s}$ , $T_A = 25^\circ\text{C}$ )	$I_{DM}$	0.8	A

### Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation	$P_D$	0.35	W
Thermal Resistance Junction-to-Air <sup>*1</sup>	$R_{\theta JA}$	310	$^\circ\text{C/W}$
Operating Junction Temperature Range	$T_J$	-55 ~ +150	$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	-55 ~ +150	$^\circ\text{C}$

Note 1: Surface-mounted on 1 inch<sup>2</sup> FR-4 board with 2OZ copper

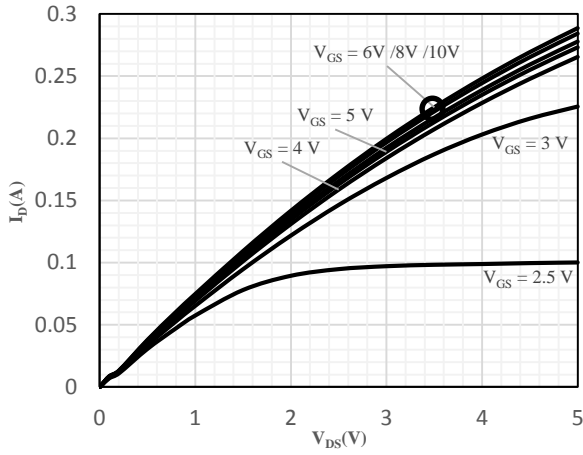


### Electrical Characteristics (@ T<sub>A</sub> = 25°C unless otherwise specified)

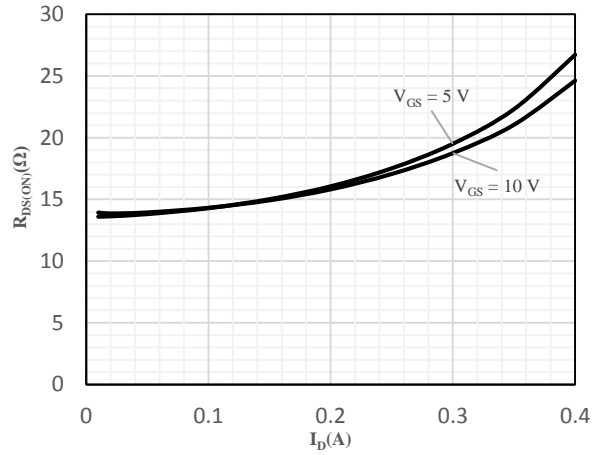
Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
V <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	240	-	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 240V, V <sub>GS</sub> = 0V	-	-	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V	-	-	±100	nA
<b>On Characteristics</b>						
R <sub>DS(ON)</sub>	Static Drain-Source On-resistance	V <sub>GS</sub> = 10V, I <sub>D</sub> = 100mA	-	13	15	Ω
		V <sub>GS</sub> = 5V, I <sub>D</sub> = 100mA	-	15	20	Ω
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA	1	1.6	2	V
C <sub>ISS</sub>	Input Capacitance	V <sub>GS</sub> = 0V V <sub>DS</sub> = 25V f = 1MHz	-	50	-	pF
C <sub>OSS</sub>	Output Capacitance		-	19	-	
C <sub>RSS</sub>	Reverse Transfer Capacitance		-	8	-	
Q <sub>G</sub>	Total Gate-Charge	V <sub>DD</sub> = 192V	-	5.6	-	nC
Q <sub>GS</sub>	Gate to Source Charge	V <sub>GS</sub> = 10V	-	0.8	-	
Q <sub>GD</sub>	Gate to Drain (Miller) Charge	I <sub>D</sub> = 0.2A	-	1.9	-	
<b>Source-Drain Diode Characteristics</b>						
V <sub>SD</sub>	Diode Forward Voltage	I <sub>SD</sub> = 100mA, V <sub>GS</sub> = 0V	-	0.8	1.5	V



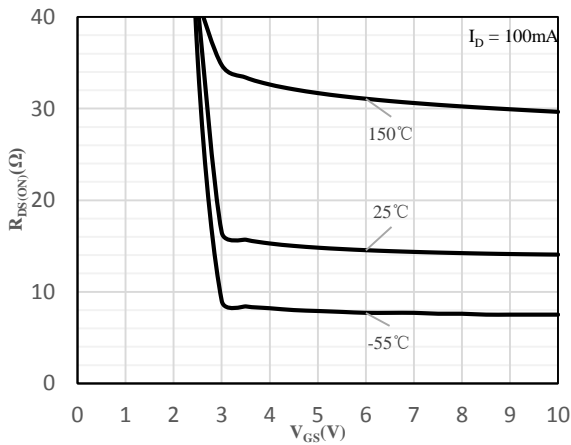
### Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)



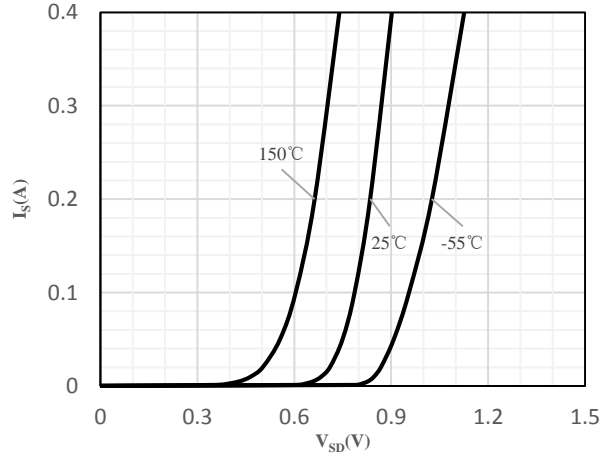
**Fig 1 Typical Output Characteristics**



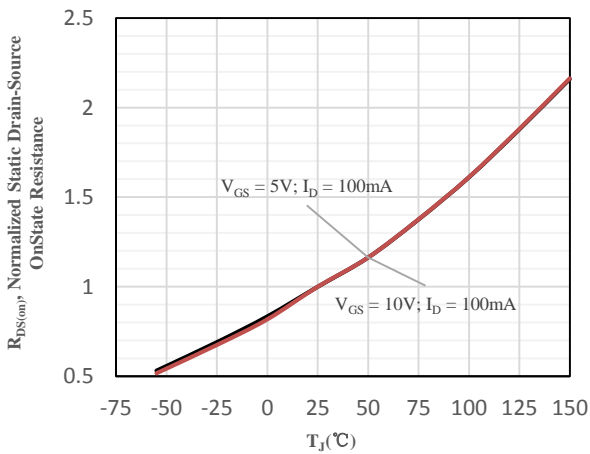
**Fig 2 On-Resistance vs. Drain Current and Gate Voltage**



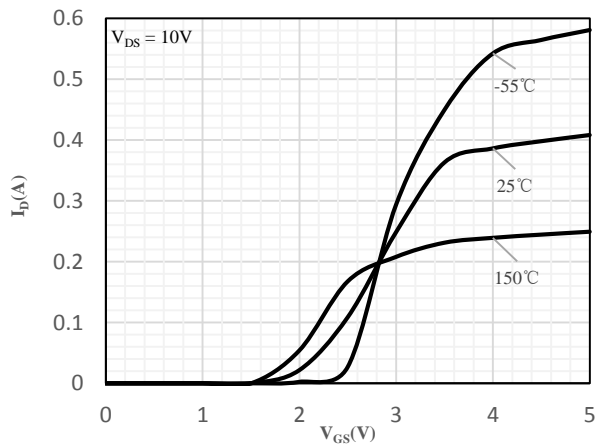
**Fig 3 On-Resistance vs. Gate-Source Voltage**



**Fig 4 Body-Diode Characteristics**



**Fig 5 Normalized On-Resistance vs. Junction Temperature**



**Fig 6 Transfer Characteristics**

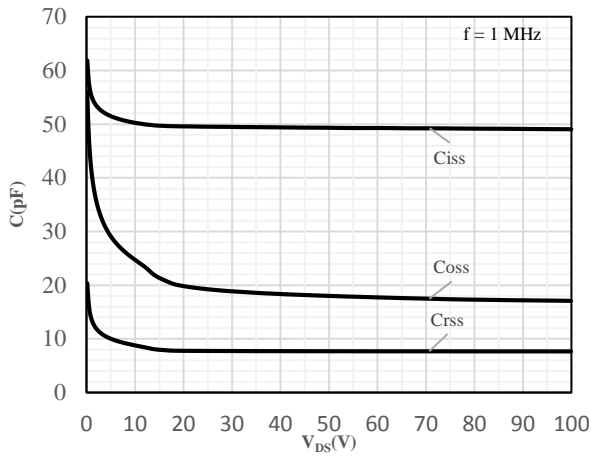


Fig 7 Capacitance Characteristics

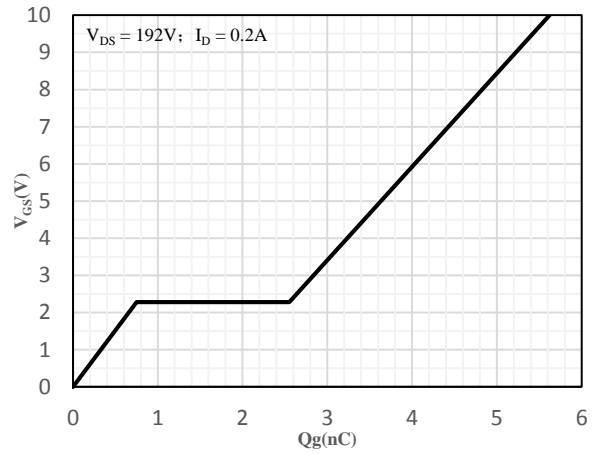


Fig 8 Gate-Charge Characteristics

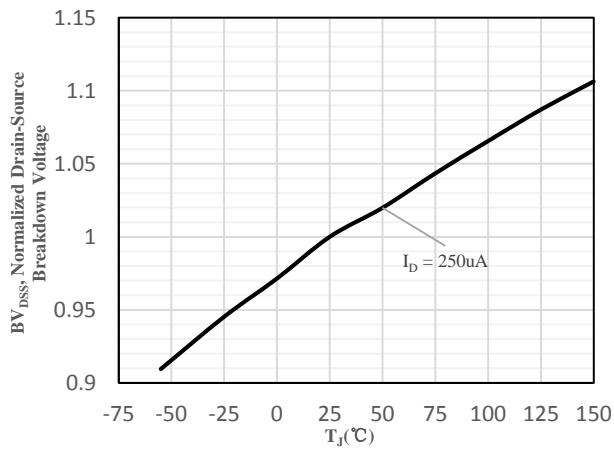


Fig 9 Normalized Breakdown Voltage vs. Junction Temperature

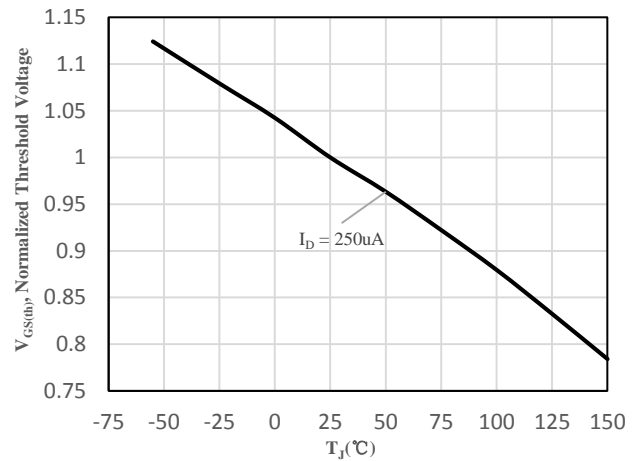


Fig 10 Normalized  $V_{GS(th)}$  vs. Junction Temperature

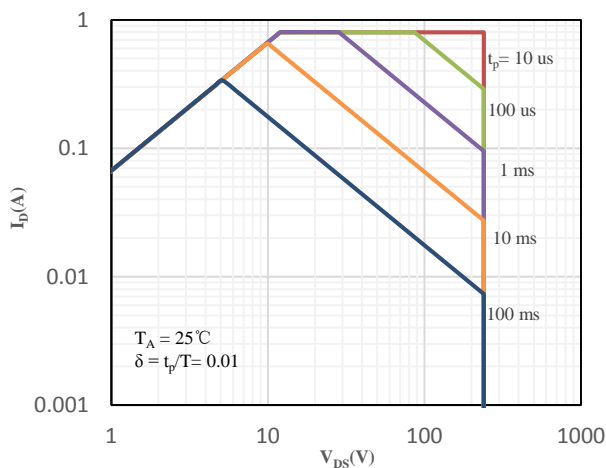


Fig 11 Safe Operation Area

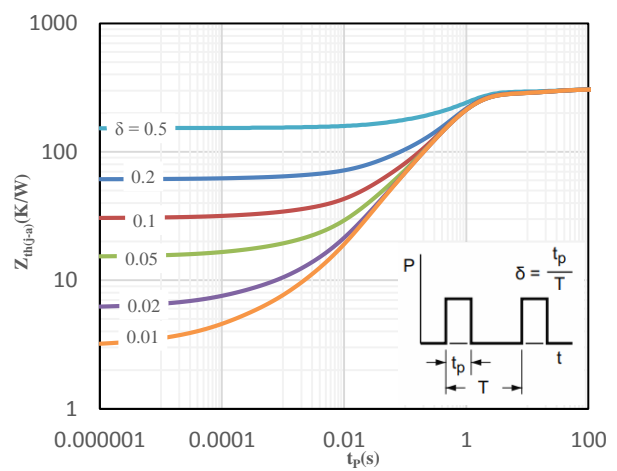
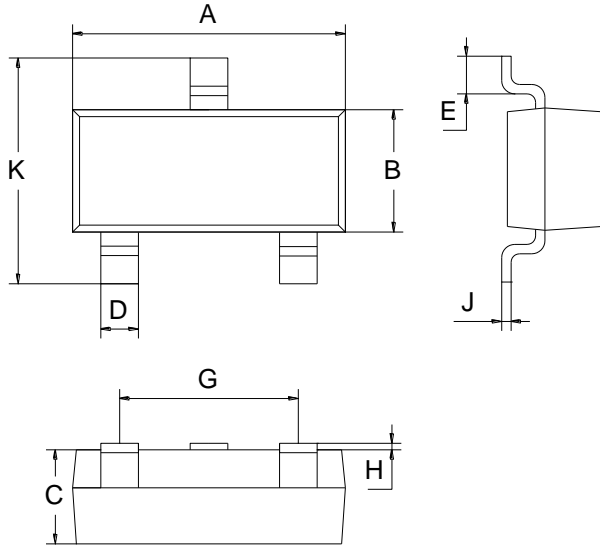


Fig 12 Maximum transient thermal impedance



### Package Outline Dimensions (Unit: mm)



SOT-23		
Dimension	Min.	Max.
A	2.70	3.10
B	1.10	1.50
C	0.90	1.10
D	0.30	0.50
E	0.35	0.48
G	1.80	2.00
H	0.02	0.10
J	0.05	0.15
K	2.20	2.60

### Mounting Pad Layout (Unit: mm)

#### SOT-23

